

isc Silicon NPN Power Transistor

BUY21

DESCRIPTION

- Collector-Emitter Breakdown Voltage-:V_{(BR)CEO}= 180V(Min.)
- Excellent Safe Operating Area
- High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

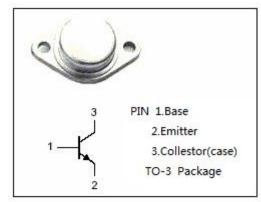
• Designed for use in switching-control amplifiers, power gates, switching regulators, converters, and inverter.

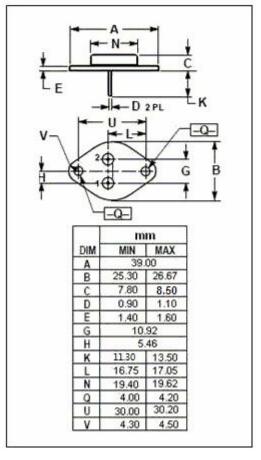
ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

ADSOLUTE MAXIMUM RATINGS(13-23 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{CBO}	Collector-Base Voltage	300	V				
V _{CEO}	Collector-Emitter Voltage	180	V				
V _{EBO}	Emitter-Base Voltage	7	V				
Ic	Collector Current-Continuous	10	Α				
I _{CM}	Collector Current-Peak	15	Α				
lΒ	Base Current-Continuous	2	Α				
P _T	Total Power Dissipation @ T₀≤25°C	85	W				
TJ	Junction Temperature	175	$^{\circ}\!\mathbb{C}$				
T _{stg}	Storage Temperature Range	-65~175	$^{\circ}$				

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.25	°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
VCEO(SUS)	Collector-Emitter Sustaining Voltage	I _C = 30mA ;I _B = 0	180			V
V _{CE} (sat)-1	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 0.5A			0.5	V
V _{CE} (sat)-2	Collector-Emitter Saturation Voltage	I _C = 10A; I _B = 1A			1.5	V
V _{BE} (sat)-1	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 0.5A			1.2	V
V _{BE} (sat)-2	Base-Emitter Saturation Voltage	I _C = 10A; I _B = 1A			1.5	V
Ісво	Collector Cutoff Current	V _{CB} =300V; I _E =0			0.1	mA
I _{EBO}	Emitter Cutoff current	V _{EB} =6V; I _C =0			0.1	mA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	60			
h _{FE-2}	DC Current Gain	I _C = 2.5A ; V _{CE} = 5V	20		300	
h _{FE-3}	DC Current Gain	I _C = 10A ; V _{CE} = 5V	10			
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5 A;V _{CE} = 10V;f _{test} = 1MHz	10			MHz

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